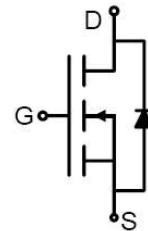


## Feature

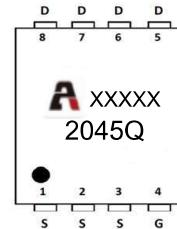
- 20V,60A
- $R_{DS(ON)} < 5.2m\Omega$  @  $V_{GS}=4.5V$  TYP=4.3 m $\Omega$
- $R_{DS(ON)} < 7.8m\Omega$  @  $V_{GS}=2.5V$  TYP=7.8 m $\Omega$
- Advanced Trench Technology
- Lead free product is acquired
- Excellent  $R_{DS(ON)}$  and Low Gate Charge



**Schematic Diagram**

## Application

- PWM applications
- Load Switch
- Power management



**Marking and pin Assignment**

## Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity (PCS)
2045Q	AP2045Q	PDFN3X3-8L	13 inch	-	5000

## ABSOLUTE MAXIMUM RATINGS ( $T_a=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	20	V
Gate-Source Voltage	$V_{GS}$	$\pm 12$	V
Continuous Drain Current ( $T_a = 25^\circ C$ )	$I_D$	60	A
Continuous Drain Current ( $T_a = 100^\circ C$ )	$I_D$	40	A
Pulsed Drain Current <sup>(1)</sup>	$I_{DM}$	200	A
Singel Pulsed Avalanche Energy <sup>(2)</sup>	$E_{AS}$	60	mJ
Power Dissipation	$P_D$	30	W
Thermal Resistance from Junction to Case <sup>(4)</sup>	$R_{eJC}$	3.2	°C/W
Junction Temperature	$T_J$	150	°C
Storage Temperature	$T_{STG}$	-55~+150	°C

**MOSFET ELECTRICAL CHARACTERISTICS( $T_a=25^\circ C$  unless otherwise noted)**

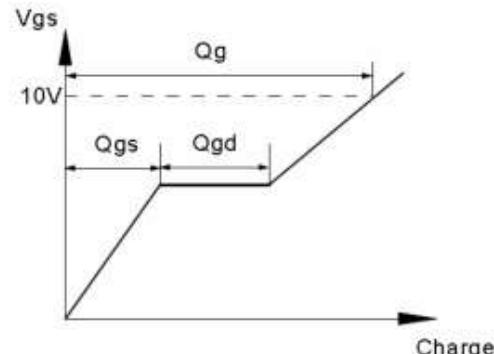
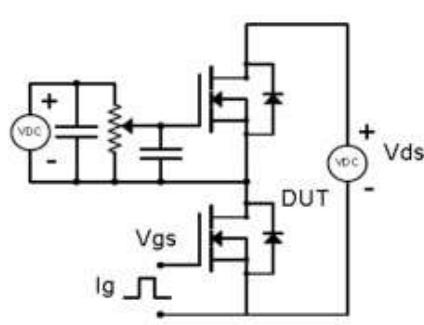
Parameter	Symbol	Test Condition	Min	Type	Max	Unit
<b>Static Characteristics</b>						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	20	-	-	V
Zero gate voltage drain current	$I_{DSS}$	$V_{DS} = 20V, V_{GS} = 0V$	-	-	1	$\mu A$
Gate-body leakage current	$I_{GSS}$	$V_{GS} = \pm 12V, V_{DS} = 0V$	-	-	$\pm 100$	nA
Gate threshold voltage <sup>(3)</sup>	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	0.5	0.7	0.9	V
Drain-source on-resistance <sup>(3)</sup>	$R_{DS(on)}$	$V_{GS} = 4.5V, I_D = 30A$	-	4.3	5.2	$m\Omega$
		$V_{GS} = 2.5V, I_D = 20A$	-	5.8	7.8	
<b>Dynamic characteristics</b>						
Input Capacitance	$C_{iss}$	$V_{DS} = 10V, V_{GS} = 0V, f = 1MHz$	-	1832	-	$pF$
Output Capacitance	$C_{oss}$		-	289	-	
Reverse Transfer Capacitance	$C_{rss}$		-	271	-	
<b>Switching characteristics</b>						
Turn-on delay time	$t_{d(on)}$	$V_{DD}=10V, I_D=25A,$ $V_{GS}=4.5V, R_G=1.8\Omega$	-	15	-	$ns$
Turn-on rise time	$t_r$		-	37	-	
Turn-off delay time	$t_{d(off)}$		-	52	-	
Turn-off fall time	$t_f$		-	21	-	
Total Gate Charge	$Q_g$	$V_{DS}=10V, ID=25A,$ $VGS=4.5V$	-	23	-	$nC$
Gate-Source Charge	$Q_{gs}$		-	4.5	-	
Gate-Drain Charge	$Q_{gd}$		-	7.3	-	
<b>Source-Drain Diode characteristics</b>						
Diode Forward voltage <sup>(3)</sup>	$V_{DS}$	$V_{GS} = 0V, I_s = 25A$	-	-	1.2	V
Diode Forward current <sup>(4)</sup>	$I_s$		-	-	60	A

**Notes:**

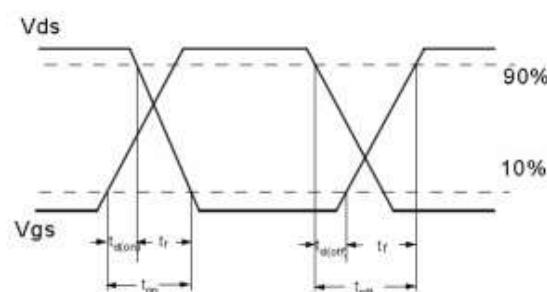
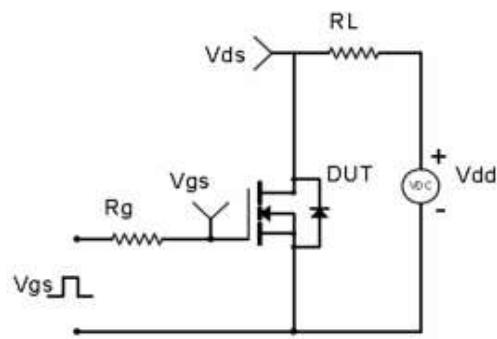
1. Repetitive Rating: pulse width limited by maximum junction temperature
2. EAS Condition: $T_J=25^\circ C, V_{DD}=15V, R_G=25\Omega, L=0.5mH$
3. Pulse Test: pulse width $\leq 300\mu s$ , duty cycle $\leq 2\%$
4. Surface Mounted on FR4 Board,  $t \leq 10$  sec

### Test Circuit & Waveform

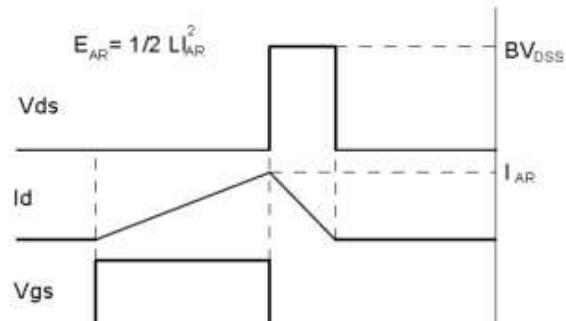
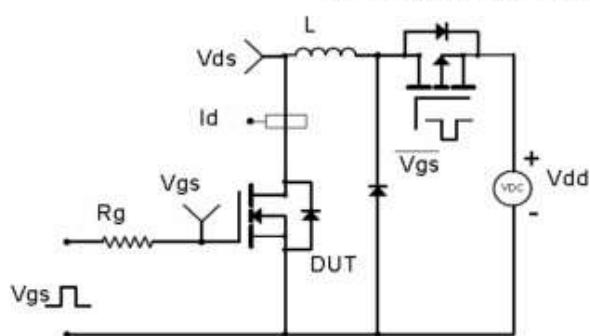
Gate Charge Test Circuit & Waveform



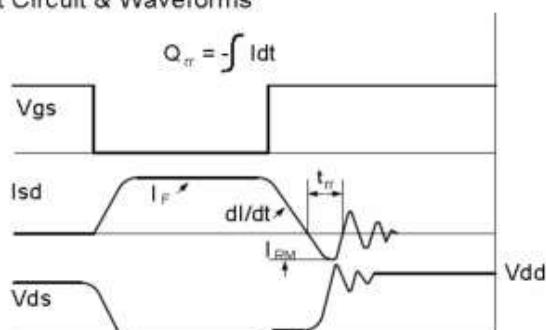
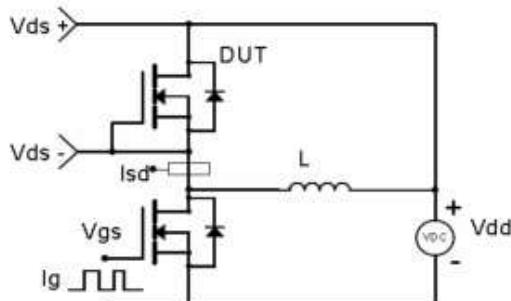
Resistive Switching Test Circuit & Waveforms



Unclamped Inductive Switching (UIS) Test Circuit & Waveforms

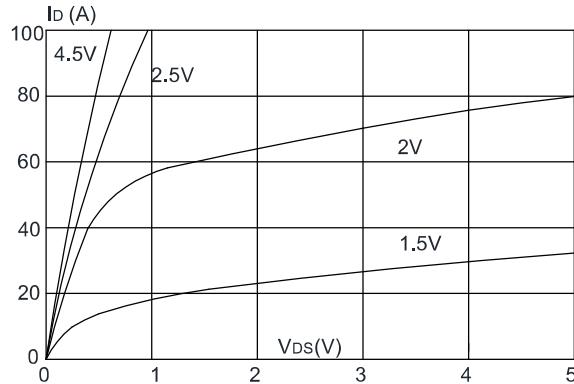


Diode Recovery Test Circuit & Waveforms

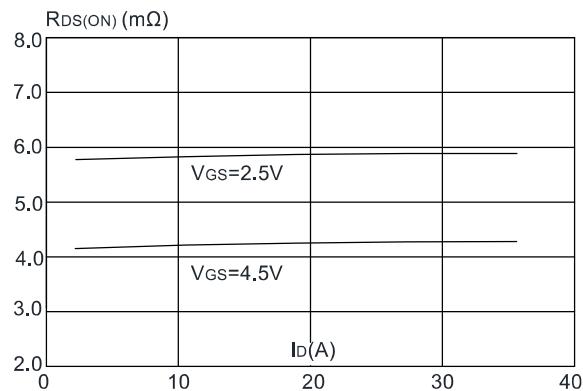


## Typical Performance Characteristics

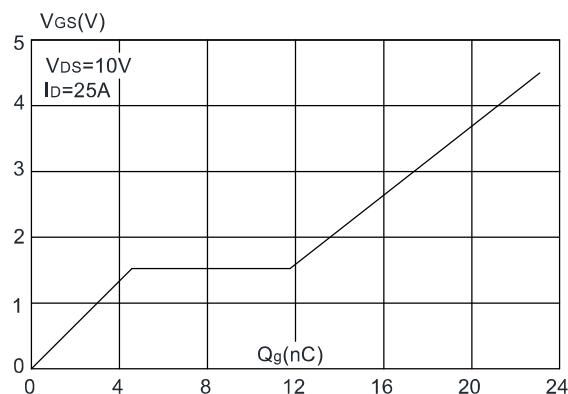
**Figure 1:** Output Characteristics



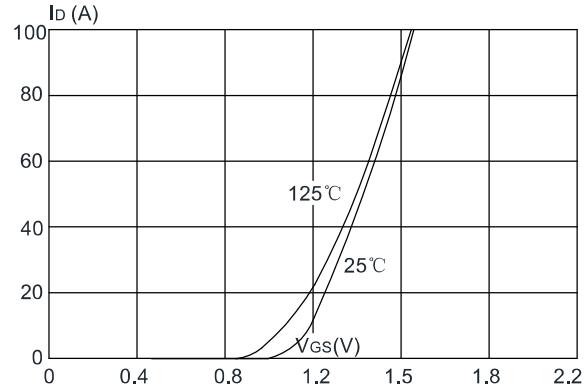
**Figure 3:** On-resistance vs. Drain Current



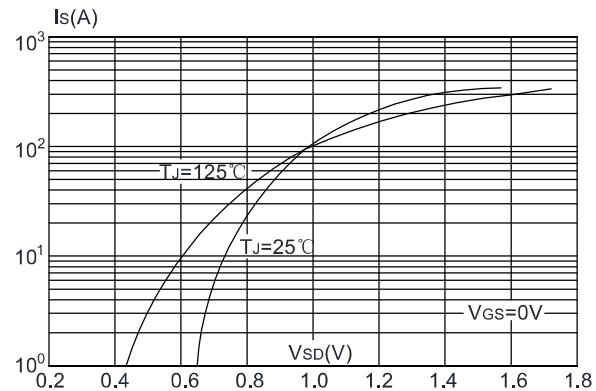
**Figure 5:** Gate Charge Characteristics



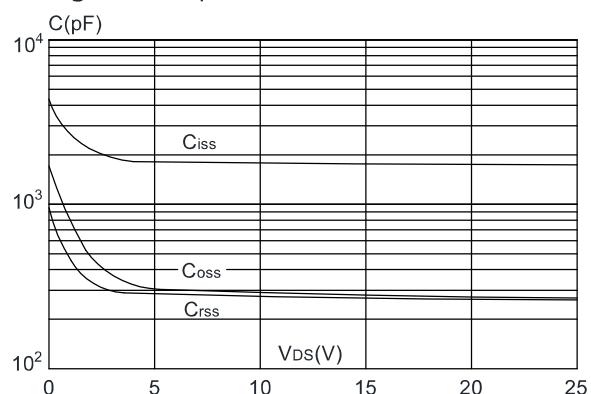
**Figure 2:** Typical Transfer Characteristics



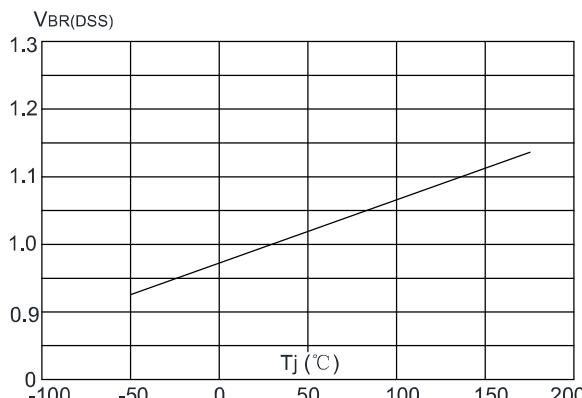
**Figure 4:** Body Diode Characteristics



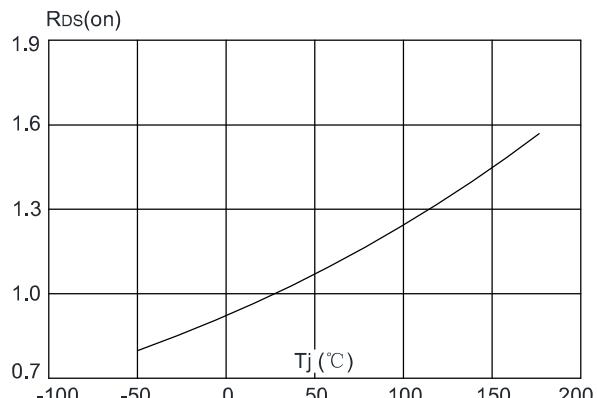
**Figure 6:** Capacitance Characteristics



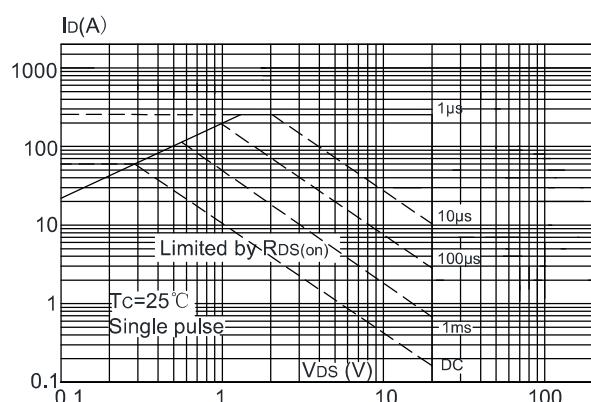
**Figure 7:** Normalized Breakdown Voltage vs. Junction Temperature



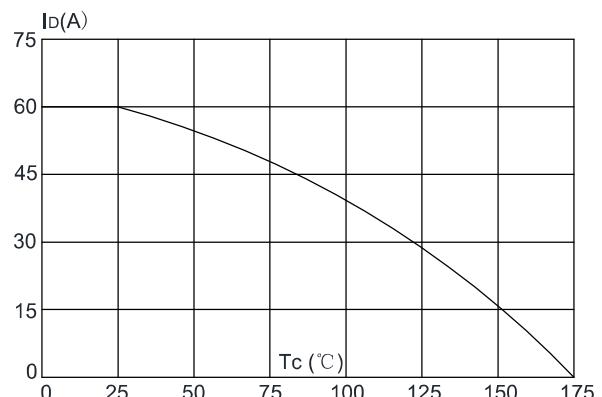
**Figure 8:** Normalized on Resistance vs. Junction Temperature



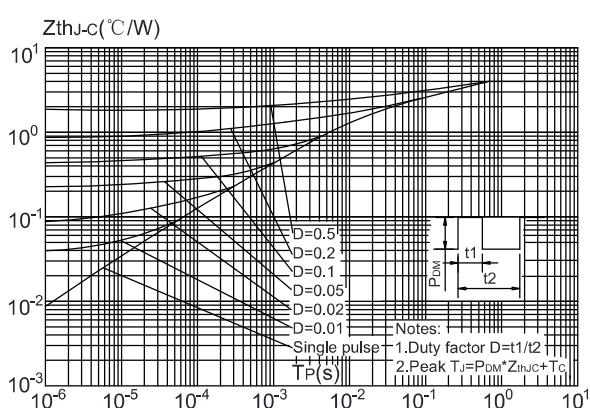
**Figure 9:** Maximum Safe Operating Area



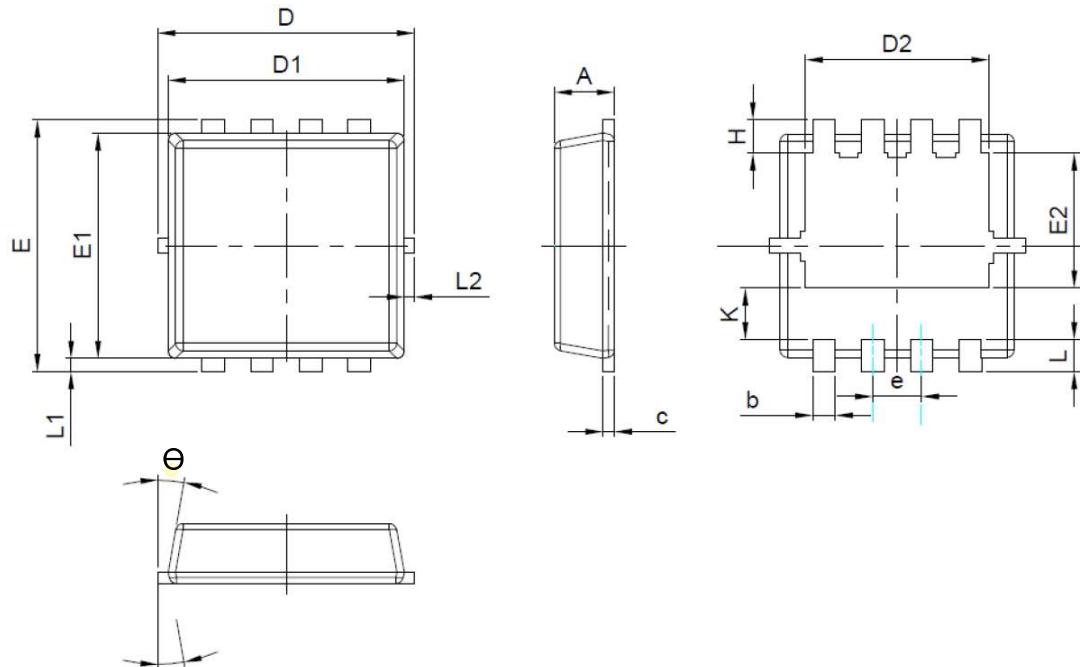
**Figure 10:** Maximum Continuous Drain Current vs. Case Temperature



**Figure 11:** Maximum Effective Transient Thermal Impedance, Junction-to-Case



## PDFN3X3-8L Package Information



**COMMON DIMENSIONS**  
( UNITS OF MEASURE = MILLIMETER )

SYMBOL	MIN	NOM	MAX
A	0.70	0.80	0.90
b	0.25	0.30	0.39
c	0.14	0.15	0.25
D	3.20	3.30	3.40
D1	3.00	3.15	3.30
D2	2.35	2.45	2.55
e	0.65 BSC		
E	3.25	3.35	3.45
E1	2.85	3.00	3.15
E2	1.635	1.735	1.835
H	0.33	0.48	0.63
K	0.585	0.685	0.785
L	0.30	0.40	0.50
L1	0.05	0.15	0.25
L2	-	-	0.15
Θ	8°	10°	12°